Diode Semiconductor Device - Page 1 of 2



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## **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Function For Which Designed:** Voltage regulator **Mounting Facility Quantity:** 2 Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 Electrode Internally-electrically Connected To Case: Cathode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.8 regulator voltage **Current Rating Per Characteristic:** 37.00 amperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:** 81349-mil-s-19500/114 government specification Shelf Life: N/a Unit Of Measure: **Demilitarization:** No

## NSN 5961-01-164-5097

Diode Semiconductor Device - Page 2 of 2

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